

BRS	1	((oxidation near (reverse or reversal or reversing)) with metal) and ((² US-PGPUB; USPAT ("6204192" "6319842" "2001049181" "20020098685" "20020167089") ; US-PGPUB; USPAT S8 and ((cu or copper) near (reduce or reduction or reduced))	6/6/05
BRS	6	S8 and ((cu or copper or cupric) adj oxide) with ((reduce or reduction o US-PGPUB; USPAT S8 and ((cu or copper or cupric) adj oxide) with ((reduce or reduction o US-PGPUB; USPAT S13 and ((cu or copper or cupric) adj oxide) with ((reduce or reduction US-PGPUB; USPAT S14 not S9	6/6/05
BRS	7	(hineman and russell).in.	6/6/05
BRS	0	(hineman and russell).in.	6/6/05
BRS	0	(hineman or russell).in. and micron.as.	6/6/05
BRS	24	(hineman).in. and micron.as.	6/6/05
BRS	21	(hineman).in. and micron.as.	6/6/05
BRS	25	S23 and damascene	6/6/05
BRS	3	S25 and damascene	6/6/05
BRS	6	S25 and damascene	6/6/05
BRS	4	(rathi and xu and huang).in.	6/6/05
BRS	4	S29 and (@ad<"20040130" or @rlad<"20040130")	6/6/05
BRS	33	S34 and ((²⁵⁷ "/\$3.cor.) or ("438"/\$3.cor.))	6/13/05
BRS	10	(plasma with hydrogen with ((before or prior) near2 barrier))	6/13/05
BRS	10	S36 and (cu or copper)	6/13/05
BRS	5	S36 and damascene	6/13/05
BRS	2	6645852	6/13/05
BRS	33	S43 and (cu or copper)	6/13/05
BRS	10	S44 and damascene	6/13/05
BRS	8	S45 and (@ad<"20040130" or @rlad<"20040130")	6/13/05
BRS	19	S48 and ((²⁵⁷ "/\$3.cor.) or ("438"/\$3.cor.))	6/13/05
BRS	2	S49 and damascene	6/13/05
BRS	9	S49 and (cu or copper)	6/13/05
BRS	7	S51 not S50	6/13/05
BRS	14	(damascene with (etch or etched or etching) with performed with chart US-PGPUB; USPAT	6/16/05
BRS	7	(damascene with (etch or etched or etching) with ((one or single) adj ct US-PGPUB; USPAT	6/16/05
BRS	1	S60 not S59	6/16/05
BRS	22	S62 and damascene	6/16/05

BRS	6	((chamber or vacuum) with (barrier near2 (remove or removed)) with p US-PGPUB; USPAT	6/16/05
BRS	21	(((tungsten adj nitride) or wn) with (copper or cu or damascene) with (d: US-PGPUB; USPAT	6/16/05
BRS	7	((parasitic adj (capacitor or capacitance)) with ("between" adj (interconn US-PGPUB; USPAT	6/16/05
BRS	9	((parasitic adj (capacitor or capacitance)) with ("between" adj (interconn US-PGPUB; USPAT	6/21/05
BRS	3	((parasitic adj (capacitor or capacitance)) with ("between" adj (interconn US-PGPUB; USPAT	6/21/05
BRS	5	((parasitic adj (capacitor or capacitance)) with ("between" adj (interconn US-PGPUB; USPAT	6/21/05
BRS	7	(micron,as,) and (microprocessor,clm,) and damascene	US-PGPUB; USPAT
BRS	27	(microprocessor,clm,) and damascene	US-PGPUB; USPAT
BRS	20	S77 not S76	US-PGPUB; USPAT
BRS	33	S79 and ("257"/\$3.cor.) or ("438"/\$3.cor.)	US-PGPUB; USPAT
BRS	32	S80 and (@ad<"20040130" or @rlad<"20040130")	US-PGPUB; USPAT
BRS	3	S81 and damascene	US-PGPUB; USPAT
BRS	19	S85 and ("257"/\$3.cor.) or ("438"/\$3.cor.) and (@ad<"20040130" or @US-PGPUB; USPAT	6/21/05
BRS	0	S87 and ("257"/\$3.cor.) or ("438"/\$3.cor.) and (@ad<"20040130" or @US-PGPUB; USPAT	6/21/05
BRS	4	S89 and ("257"/\$3.cor.) or ("438"/\$3.cor.) and (@ad<"20040130" or @US-PGPUB; USPAT	6/21/05
BRS	4	S92 and ("257"/\$3.cor.) or ("438"/\$3.cor.) and (@ad<"20040130" or @US-PGPUB; USPAT	6/23/05
BRS	11	(US-20010034127-\$ or US-20020111037-\$ or US-20020177303-\$).did. US-PGPUB; USPAT	6/23/05
BRS	0	S99 and triple	US-PGPUB; USPAT
BRS	6	S118 and ("257"/\$3.cor.) or ("438"/\$3.cor.)	US-PGPUB; USPAT
BRS	0	S123 and ("428"/\$3.cor.)	US-PGPUB; USPAT
BRS	19	integrated adj circuit adj coupled adj microprocessor	US-PGPUB; USPAT
BRS	12	integrated adj circuit adj connected adj microprocessor	US-PGPUB; USPAT
BRS	2	S135 and damascene	US-PGPUB; USPAT
BRS	4	S135 and (microprocessor with ("same" adj (chip or substrate)))	US-PGPUB; USPAT
BRS	0	S142 and ("428"/\$3.cor.)	US-PGPUB; USPAT
BRS	6	S142 and semiconductor	US-PGPUB; USPAT
BRS	0	S148 and ("257"/\$3.cor.) or ("438"/\$3.cor.)	US-PGPUB; USPAT
BRS	3	S148 and semiconductor	US-PGPUB; USPAT
BRS	0	S156 and ("257"/\$3.cor.) or ("438"/\$3.cor.)	US-PGPUB; USPAT
BRS	21	(\$1boc or tboc) and ("257"/\$3.cor.) or ("438"/\$3.cor.)	US-PGPUB; USPAT
BRS	4	((hf or hydro\$1fluoric)) and S158	US-PGPUB; USPAT

					6/25/05
BRS	1	((hf or hydro\$1fluoric) with (resist or photo\$1resist) with best)	US-PGPUB; USPAT	US-PGPUB; USPAT	6/25/05
BRS	0	((hf or hydro\$1fluoric) with (resist or photo\$1resist) with superb)	US-PGPUB; USPAT	US-PGPUB; USPAT	6/25/05
BRS	14	((hf or hydro\$1fluoric) with (resist or photo\$1resist) with good)	US-PGPUB; USPAT	US-PGPUB; USPAT	6/25/05
BRS	0	((hf or hydro\$1fluoric) with (resist or photo\$1resist) with "since")	US-PGPUB; USPAT	US-PGPUB; USPAT	6/25/05
BRS	5	((hf or hydro\$1fluoric) with (resist or photo\$1resist) with quick)	US-PGPUB; USPAT	US-PGPUB; USPAT	6/25/05
BRS	1	S170 and damascene	US-PGPUB; USPAT	US-PGPUB; USPAT	6/25/05
BRS	1	S168 and damascene	US-PGPUB; USPAT	US-PGPUB; USPAT	6/25/05
BRS	1	S167 and damascene	US-PGPUB; USPAT	US-PGPUB; USPAT	6/25/05
BRS	4	S174 and damascene	US-PGPUB; USPAT	US-PGPUB; USPAT	6/25/05
BRS	30	((microprocessor) with ("same" adj (chip or substrate)) with embedded	US-PGPUB; USPAT	US-PGPUB; USPAT	6/25/05
BRS	30	S180 and (@ad<"20040130" or @rlad<"20040130")	US-PGPUB; USPAT	US-PGPUB; USPAT	6/25/05
BRS	3	S181 and ((257"/\$3.cor.) or ("438"/\$3.cor.))	US-PGPUB; USPAT	US-PGPUB; USPAT	6/25/05
BRS	14	S184 and ((257"/\$3.cor.) or ("438"/\$3.cor.))	US-PGPUB; USPAT	US-PGPUB; USPAT	6/25/05
BRS	4	(memory with damascene with density)	US-PGPUB; USPAT	US-PGPUB; USPAT	6/25/05
BRS	9	(memory with damascene with resistance)	US-PGPUB; USPAT	US-PGPUB; USPAT	6/25/05